2-input AND Gate

# HITACHI

ADE-205-328C (Z) 4th. Edition April 2000

#### Description

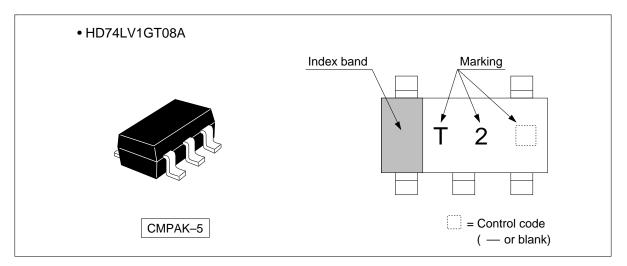
The HD74LV1GT08A is high speed CMOS two input AND gate using silicon gate CMOS process. With CMOS low power dissipation, it provides high speed equivalent to LS–TTL series. The internal circuit of three stages construction with buffer provides wide noise margin and stable output. Low voltage and high speed operation is suitable for the battery powered products (e.g., notebook computers), and the low power consumption extends the battery life.

#### Features

- The basic gate function is lined up as hitachi uni logic series.
- Supplied on emboss taping for high speed automatic mounting.
- TTL compatible input level. Supply voltage range : 4.5 to 5.5 V Operating temperature range : -40 to +85°C
- All inputs  $V_{IH}$  (Max.) = 5.5 V (@V<sub>CC</sub> = 0 V to 5.5 V) All outputs  $V_0$  (Max.) = 5.5 V (@V<sub>CC</sub> = 0 V)
- Output current  $\pm 12 \text{ mA}$  (@V<sub>CC</sub> = 4.5 V to 5.5 V)
- All the logical input has hysteresis voltage for the slow transition.



#### **Outline and Article Indication**



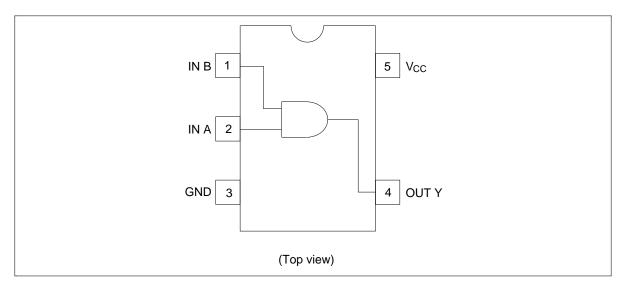
#### **Function Table**

Inputs		Output Y			
Α	В				
L	L	L			
Н	L	L			
L	Н	L			
Н	Н	Н			

H : High level

L : Low level

#### **Pin Arrangement**



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## **Absolute Maximum Ratings**

Item	Symbol	Ratings	Unit	Test Conditions
Supply voltage	V <sub>cc</sub>	-0.5 to 7.0	V	
Input voltage	V <sub>IN</sub>	-0.5 to 7.0	V	
Output voltage	V <sub>OUT</sub>	-0.5 to V <sub>cc</sub> + 0.5	V	Output : H or L
		-0.5 to 7.0		V <sub>cc</sub> : OFF
Input diode current	I <sub>IK</sub>	-20	mA	
Output diode current	I <sub>ok</sub>	±50	mA	
Output current	I <sub>OUT</sub>	±25	mA	
V <sub>cc</sub> , GND current	I <sub>cc</sub> or I <sub>GND</sub>	±50	mA	
Power dissipation	P <sub>T</sub>	200	mW	
Storage temperature	Tstg	–65 to 150	°C	

#### **Recommended Operating Conditions**

Item	Symbol	Ratings	Unit
Supply voltage	V <sub>cc</sub>	4.5 to 5.5	V
Input voltage	V <sub>IN</sub>	0 to 5.5	V
Output voltage	V <sub>OUT</sub>	0 to V <sub>cc</sub>	V
Operating temperature	T <sub>opr</sub>	-40 to +85	°C
Input rise / fall time	t <sub>r</sub> , t <sub>f</sub>	0 to 20 (V <sub>cc</sub> = 4.5 to 5.5 V)	ns

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#### **Electrical Characteristic**

#### • Ta = -40 to $85^{\circ}C$

Item	Symbol	V <sub>cc</sub> (V) *	Min	Тур	Max	Unit	Test condition
Input voltage	V <sub>IH</sub>	4.5 to 5.5	2.0	_	_	V	
	V <sub>IL</sub>	4.5 to 5.5			0.8		
Hysteresis voltage	V <sub>H</sub>	5.0	_	0.15	_	V	$V_T^+ - V_T^-$
Output voltage	V <sub>OH</sub>	Min to Max	V <sub>cc</sub> –0.1	_		V	I <sub>OH</sub> = -50 μA
		4.5	3.8				I <sub>он</sub> = –12 mA
	V <sub>ol</sub>	Min to Max	_	_	0.1		I <sub>oL</sub> = 50 μA
		4.5		_	0.55		I <sub>oL</sub> = 12 mA
Input current	I <sub>IN</sub>	0 to 5.5			±1	μA	$V_{IN} = 5.5 \text{ V or GND}$
Quiescent supply current	I <sub>cc</sub>	5.5	—	—	10	μA	$V_{IN} = V_{CC}$ or GND, $I_{O} = 0$
	$\Delta I_{cc}$	5.5	_		1.5	mA	One input $V_{IN} = 3.4 V$ , other input $V_{CC}$ or GND
Output leakage current	I <sub>OFF</sub>	0	_	_	5	μA	V <sub>o</sub> = 5.5 V
Input capacitance	CIN	5.0		2.5	_	pF	$V_{IN} = V_{CC}$ or GND

Note: For conditions shown as Min or Max, use the appropriate values under recommended operating conditions.

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#### **Switching Characteristics**

•  $V_{CC} = 5.0 \pm 0.5 \text{ V}$ 

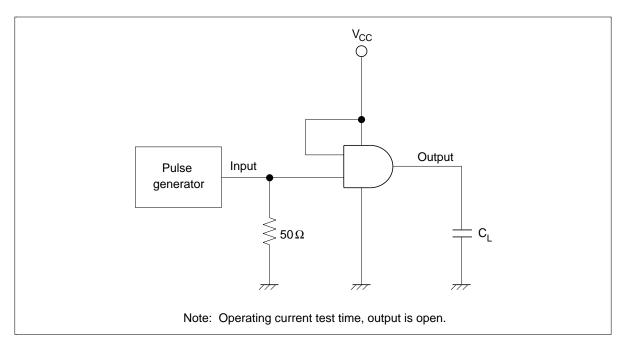
ltem	Symbol	$T_a = 2$	$T_a = 25^{\circ}C$ $T_a = -40 \text{ to } 85^{\circ}C$		Unit	Test	FROM	то		
		Min	Тур	Max	Min	Max	-	Conditions	(Input)	(Output)
Propagation	t <sub>PLH</sub>	—	5.0	6.9	1.0	8.0	ns	$C_L = 15 \text{ pF}$	A or B	Y
delay time	t <sub>PHL</sub>	_	5.5	7.9	1.0	9.0	_	C <sub>L</sub> = 50 pF	_	

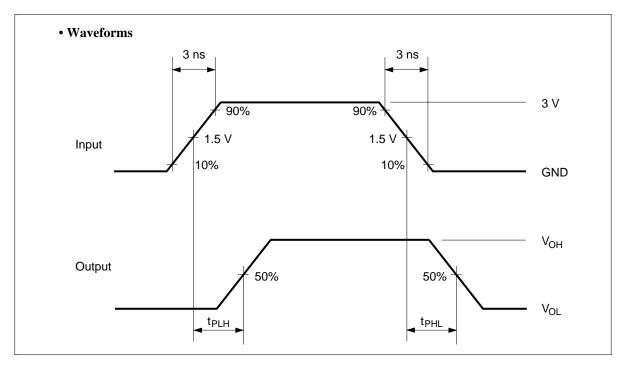
#### **Operating Characteristics**

•  $C_L = 50 \ pF$ 

Item	Symbol	V <sub>cc</sub> (V)	$T_a = 25^{\circ}C$			Unit	Test Conditions	
			Min	Тур	Max			
Power dissipation capacitance	$C_{PD}$	5.0	_	10.0	_	pF	f = 10 MHz	

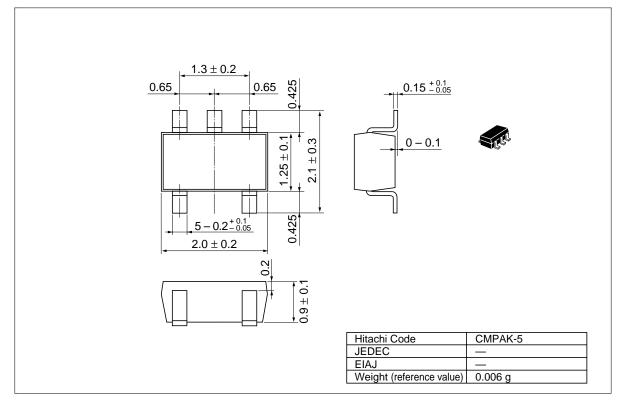
#### **Test Circuit**





#### **Package Dimensions**

Unit : mm



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Semiconductor & Integrated Circuits. Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109 URL NorthAmerica http:semiconductor.hitachi.com/ http://www.hitachi-eu.com/hel/ecg Europe http://www.has.hitachi.com.sg/grp3/sicd/index.htm http://www.hitachi.com.tw/E/Product/SICD\_Frame.htm Asia (Singapore) Asia (Taiwan) Asia (HongKong) http://www.hitachi.com.hk/eng/bo/grp3/index.htm http://www.hitachi.co.jp/Sicd/index.htm Japan For further information write to: Hitachi Semiconductor Hitachi Europe GmbH Hitachi Asia Pte. Ltd. Hitachi Asia (Hong Kong) Ltd. (America) Inc. Electronic components Group 16 Collyer Quay #20-00 179 East Tasman Drive, Dornacher Stra§e 3 Hitachi Tower San Jose,CA 95134 D-85622 Feldkirchen, Munich Singapore 049318 Tel: <1> (408) 433-1990 Fax: <1>(408) 433-0223 Germany Tel: 535-2100 Tel: <49> (89) 9 9180-0 Fax: 535-1533 Fax: <49> (89) 9 29 30 00 Hitachi Asia Ltd. Hitachi Europe Ltd. Taipei Branch Office Electronic Components Group. Whitebrook Park 3F, Hung Kuo Building. No.167, Tun-Hwa North Road, Taipei (105) Lower Cookham Road Tel: <886> (2) 2718-3666 Maidenhead

Berkshire SL6 8YA, United Kingdom Tel: <44> (1628) 585000 Fax: <44> (1628) 778322

Group III (Electronic Components) 7/F., North Tower, World Finance Centre, Harbour City, Canton Road, Tsim Sha Tsui, Kowloon, Hong Kong Tel: <852> (2) 735 9218 Fax: <852> (2) 730 0281 Telex: 40815 HITEC HX

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Fax: <886> (2) 2718-8180